MJL21193 (PNP), MJL21194 (NPN)

Silicon Power Transistors

The MJL21193 and MJL21194 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

Features

- Total Harmonic Distortion Characterized
- High DC Current Gain
- Excellent Gain Linearity
- High SOA
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS			
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	250	Vdc
Collector-Base Voltage	V _{CBO}	400	Vdc
Emitter-Base Voltage	V _{EBO}	5	Vdc
Collector-Emitter Voltage - 1.5 V	V _{CEX}	400	Vdc
Collector Current – Continuous	I _C	16	Adc
Collector Current – Peak (Note 1)	I _{CM}	30	Adc
Base Current – Continuous	Ι _Β	5	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D	200 1.43	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	−65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Pulse Test: Pulse Width = $300 \ \mu$ s, Duty Cycle $\leq 2\%$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.7	°C/W



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16 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS, 200 WATTS



MARKING DIAGRAM



~	- Assembly Location
YY	= Year
WW	= Work Week
G	= Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MJL21193G	TO-264 (Pb-Free)	25 Units / Rail
MJL21194G	TO-264 (Pb-Free)	25 Units / Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_C = $25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$		V _{CEO(sus)}	250	-	-	Vdc
Collector Cutoff Current $(V_{CE} = 200 \text{ Vdc}, I_B = 0)$		I _{CEO}	-	-	100	μAdc
Emitter Cutoff Current ($V_{CE} = 5 \text{ Vdc}, I_C = 0$)		I _{EBO}	-	-	100	μAdc
Collector Cutoff Current (V _{CE} = 250 Vdc, V _{BE(off)} = 1.5 Vdc)	ICEX	-	-	100	μAdc	
SECOND BREAKDOWN						
Second Breakdown Collector Current with Base Fo ($V_{CE} = 50$ Vdc, t = 1 s (non-repetitive) ($V_{CE} = 80$ Vdc, t = 1 s (non-repetitive)	rward Biased	I _{S/b}	4.0 2.25	-		Adc
ON CHARACTERISTICS						
DC Current Gain ($I_C = 8 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$) ($I_C = 16 \text{ Adc}, I_B = 5 \text{ Adc}$)		h _{FE}	25 8		75 -	
Base–Emitter On Voltage (I _C = 8 Adc, V _{CE} = 5 Vdc)		V _{BE(on)}	_	-	2.2	Vdc
Collector–Emitter Saturation Voltage ($I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc}$) ($I_C = 16 \text{ Adc}, I_B = 3.2 \text{ Adc}$)		V _{CE(sat)}		-	1.4 4	Vdc
DYNAMIC CHARACTERISTICS						
Total Harmonic Distortion at the Output V_{RMS} = 28.3 V, f = 1 kHz, P_{LOAD} = 100 W_{RMS}	h _{FE}	T _{HD}				%
(Matched pair h _{FE} = 50 @ 5 A/5 V)	unmatched h _{FE} matched		-	0.8 0.08	-	
Current Gain Bandwidth Product ($I_C = 1 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 1 \text{ MHz}$)		fT	4	_	_	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)		C _{ob}	-	-	500	pF







TYPICAL CHARACTERISTICS







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Figure 5. DC Current Gain, $V_{CE} = 5 V$







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TYPICAL CHARACTERISTICS







Figure 10. Typical Saturation Voltages



Figure 11. Typical Base-Emitter Voltage



Figure 13. Active Region Safe Operating Area

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Figure 12. Typical Base–Emitter Voltage

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate IC - VCE limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 150^{\circ}$ C; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

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Figure 14. MJL21193 Typical Capacitance

Figure 15. MJL21194 Typical Capacitance







Figure 17. Total Harmonic Distortion Test Circuit





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